SNx5175 Quadruple Differential Line Receivers

1 Features

- Meet or exceed the requirements of ANSI standard EIA/TIA-422-B, RS-423-B, and RS-485
- Meet ITU recommendations V.10, V.11, X.26, and X.27
- Designed for multipoint bus transmission on long bus lines in noisy environments
- 3-state outputs
- Common-mode input voltage range: −12 V to 12 V
- Input sensitivity: ±200 mV
- Input hysteresis: 50-mV typical
- High input impedance: 12-kΩ minimum
- Operate from single 5-V supply
- Low-power requirements
- Plug-in replacement for MC3486

2 Applications

- Motor drives
- Factory automation and control

3 Description

The SN65175 and SN75175 are monolithic quadruple differential line receivers with 3-state outputs. They are designed to meet the requirements of ANSI Standards EIA/TIA-422-B, RS-423-B, and RS-485, and several ITU recommendations. These standards are for balanced multipoint bus transmission at rates up to 10 megabits per second. Each of the two pairs of receivers has a common active-high enable.

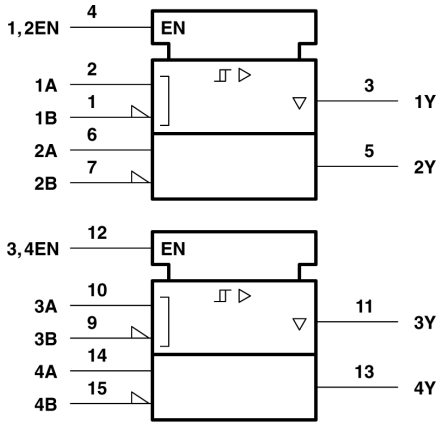
The receivers feature high input impedance, input hysteresis for increased noise immunity, and input sensitivity of ±200 mV over a common-mode input voltage range of ±12 V. The SN65175 and SN75175 are designed for optimum performance when used with the SN75172 or SN75174 quadruple differential line drivers.

The SN65175 is characterized for operation from −40°C to 85°C. The SN75175 is characterized for operation from 0°C to 70°C.

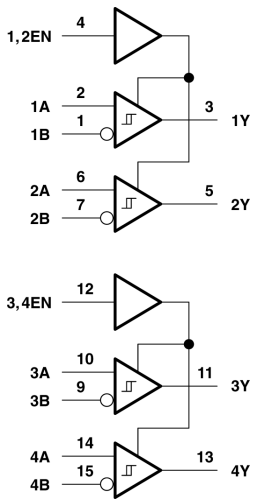
Package Information

PART NUMBER	PACKAGE(1)	PACKAGE SIZE(2)
SN65175	D (SOIC, 16)	9.9 mm × 6 mm
SN75175	N (PDIP, 16)	19.3 mm × 9.4 mm
	D (SOIC, 16)	9.9 mm × 6 mm
	NS (SOP, 16)	10.2 mm × 7.8 mm

(1) For all more information, see Section 11.
(2) The package size (length × width) is a nominal value and includes pins, where applicable.



Logic Symbol [1]



Logic Diagram (Positive Logic)

[1] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Table of Contents

4 Pin Configuration and Functions

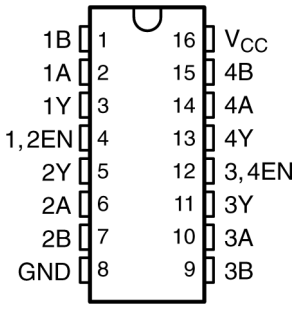


Figure 4-1. D, N, or NS Package (Top View)

Table 4-1. Pin Functions

PIN		TYPE(1)	DESCRIPTION
NAME	NO.		
1B	1	I	Channel 1 Differential Receiver Inverting Input
1A	2	I	Channel 1 Differential Receiver Non-Inverting Input
1Y	3	O	Channel 1 Single Ended Output
1,2EN	4	I	Active High Enable for Channels 1 and 2
2Y	5	O	Channel 2 Single Ended Output
2A	6	I	Channel 2 Differential Receiver Non-Inverting Input
2B	7	I	Channel 2 Differential Receiver Inverting Input
GND	8	GND	Device GND
3B	9	I	Channel 3 Differential Receiver Inverting Input
3A	10	I	Channel 3 Differential Receiver Non-Inverting Input
3Y	11	O	Channel 3 Single Ended Output
3,4EN	12	I	Active High Enable for Channels 3 and 4
4Y	13	O	Channel 4 Single Ended Output
4A	14	I	Channel 4 Differential Receiver Non-Inverting Input
4B	15	I	Channel 4 Differential Receiver Inverting Input
V_{CC}	16	PWR	Device V_{CC} (4.75 V to 5.25 V)

(1) Signal Types: I = Input, O = Output, I/O = Input or Output.

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIX	MAX	UNIT
V_{CC} (2)	Supply voltage			7	V
V_I	Input voltage (A or B inputs)			±25	V
V_{ID} (3)	Differential input voltage			±25	V
$V_{I(EN)}$	Enable input voltage			7	V
I_{OL}	Low-level output current			50	mA
	Continuous total dissipation		See *Dissipation Rating* table		
T_A	Operating free-air temperature range:	SN65175	−40	85	°C
		SN75175	0	70	°C
	Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds			260	°C
T_{stg}	Storage temperature range		−65	150	°C

(1) Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) All voltage values, except differential input voltage, are with respect to network ground terminal.
(3) Differential-input voltage is measured at the noninverting input with respect to the corresponding inverting input.

5.2 Dissipation Rating

PACKAGE	$T_A \le 25°C$ POWER RATING	DERATING FACTOR	$T_A = 70°C$ POWER RATING	$T_A = 85°C$ POWER RATING
D	950 mW	7.6 mW/°C	608 mW	494 mW
N	1150 mW	9.2 mW/°C	736 mW	598 mW

5.3 Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V_{CC}		4.75	5	5.25	V
Common-mode input voltage, V_{IC}				±12	V
Differential input voltage, V_{ID}				±12	V
High-level enable-input voltage, V_{IH}		2			V
Low-level enable-input voltage, V_{IL}				0.8	V
High-level output current, I_{OH}				−400	µA
Low-level output current, I_{OL}				16	mA
Operating free-air temperature, T_A	SN65175	−40		85	°C
	SN75175	0		70	

5.4 Thermal Information

THERMAL METRIC[1]		D (SOIC)	N (PDIP)	NS (SOP)	UNIT
		16-PINS			
$R_{\theta JA}$	Junction-to-ambient thermal resistance	84.6	60.6	88.5	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	43.5	48.1	46.2	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	43.2	40.6	50.7	°C/W
ψ_{JT}	Junction-to-top characterization parameter	10.4	27.5	13.5	°C/W
ψ_{JB}	Junction-to-board characterization parameter	42.8	40.3	50.3	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC package thermal metrics* application report.

5.5 Electrical Characteristics

over recommended ranges of common-mode input voltage, supply voltage and operating free-air temperature

PARAMETER		TEST CONDITIONS			MIN	TYP[1]	MAX	UNIT
V_{IT+}	Positive-going input threshold voltage	V_O = 2.7 V,	I_O = –0.4 mA				0.2	V
V_{IT-}	Negative-going input threshold voltage	V_O = 0.5 V,	I_O = 16 mA		–0.2[2]			V
V_{hys}	Hysteresis voltage (V_{IT+} - V_{IT-})	See Figure 5-1				50		mV
V_{IK}	Enable-input clamp voltage	I_I = –18 mA					-1.5	V
V_{OH}	High-level output voltage	V_{ID} = 200 mV,	I_{OH} = –400 µA,	See Figure 6-1	2.7			V
V_{OL}	Low-level output voltage	V_{ID} = –200 mV,	See Figure 6-1	I_{OL} = 8 mA			0.45	V
				I_{OL} = 16 mA			0.5	
I_{OZ}	High-impedance-state output current	V_O = 0.4 V to 2.4 V					±20	µA
I_I	Line input current	Other input at 0 V,	See [4]	V_I = 12 V			1	mA
				V_I = –7 V			-0.8	
I_{IH}	High-level enable-input current	V_{IH} = 2.7 V					20	µA
I_{IL}	Low-level enable-input current	V_{IL} = 0.4 V					-100	µA
r_i	Input resistance				12			kΩ
I_{OS}	Short-circuit output current[3]				-15		-85	mA
I_{CC}	Supply current	Outputs disabled					70	mA

(1) All typical values are at V_{CC} = 5 V, T_A = 25°C.
(2) The algebraic convention, in which the less positive (more negative) limit is designated as minimum, is used in this data sheet for threshold voltage levels only.
(3) Not more than one output should be shorted at a time, and the duration of the short circuit should not exceed one second.
(4) Refer to ANSI Standards EIA/TIA-422-B, RS-423-B, and RS-485 for exact conditions.

5.6 Switching Characteristics

V_{CC} = 5 V, C_L = 15 pF, T_A = 25°C

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{PLH}	Propagation delay time, low- to high-level output	See Figure 6-2		22	35	ns
t_{PHL}	Propagation delay time, high- to low-level output			25	35	ns
t_{PZH}	Output enable time to high level	See Figure 6-3		13	30	ns
t_{PZL}	Output enable time to low level			19	30	ns
t_{PHZ}	Output disable time from high level	See Figure 6-3		26	35	ns
t_{PLZ}	Output disable time from low level			25	35	ns

5.7 Typical Characteristics

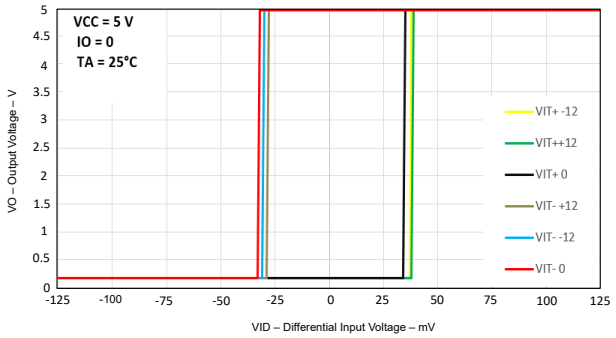


Figure 5-1. Output Voltage vs Differential Input Voltage

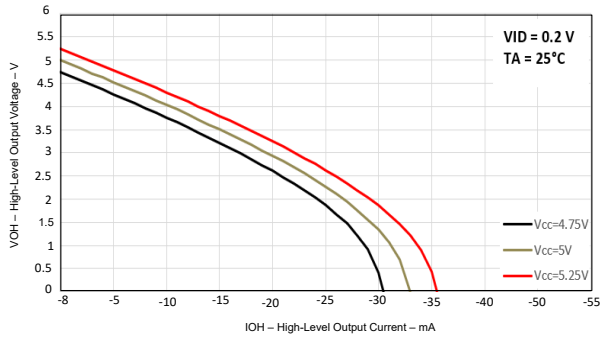


Figure 5-2. High-level Output Voltage vs High-level Output Current

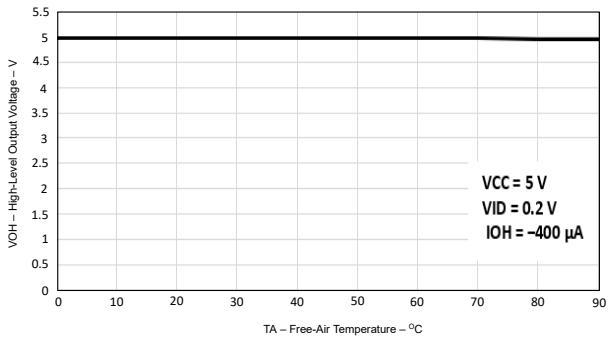


Figure 5-3. High-level Output Voltage vs Free-air Temperature 5

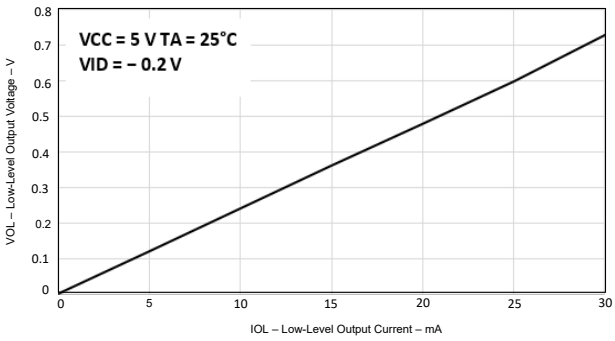


Figure 5-4. Low-level Output Voltage vs Low-level Output Current

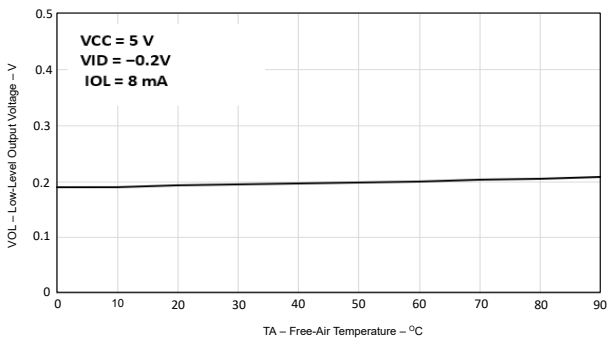


Figure 5-5. Low-level Output Voltage vs Free-air Temperature

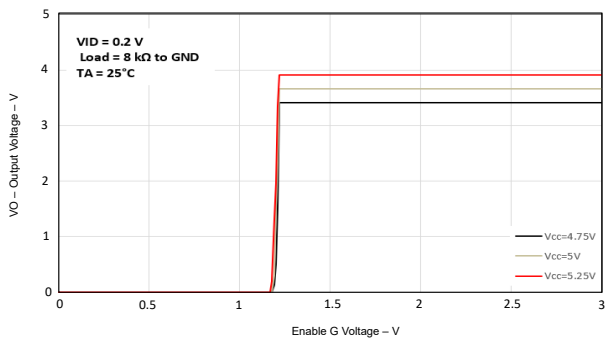


Figure 5-6. Output Voltage vs Enable G Voltage

5.7 Typical Characteristics (continued)

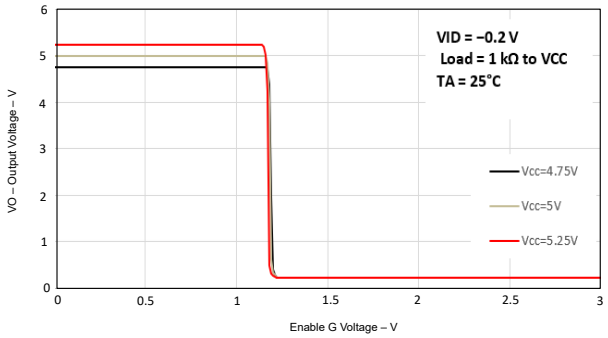


Figure 5-7. Output Voltage vs Enable G Voltage

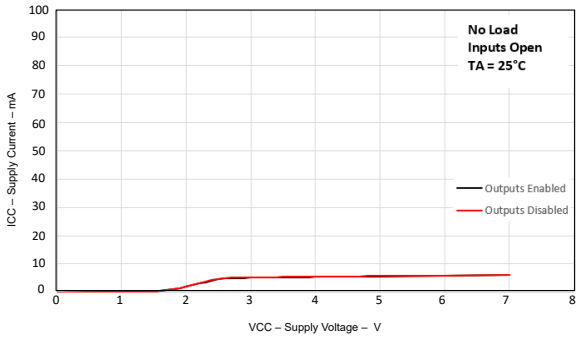


Figure 5-8. Supply Current (All Receivers) vs Supply Voltage

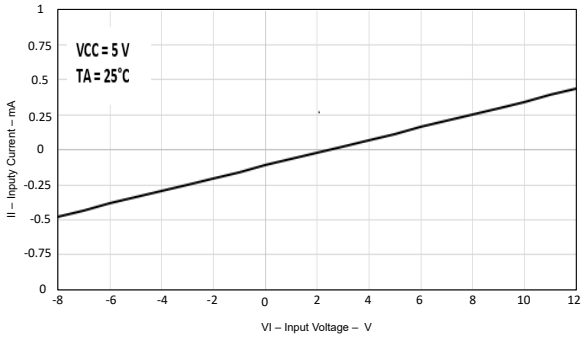


Figure 5-9. Input Current vs Input Voltage

6 Parameter Measurement Information

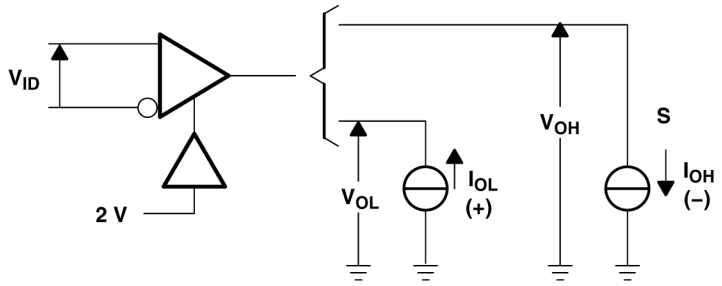
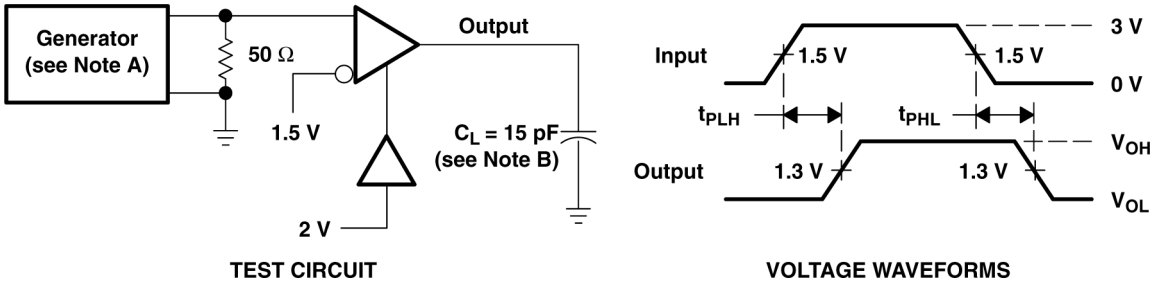


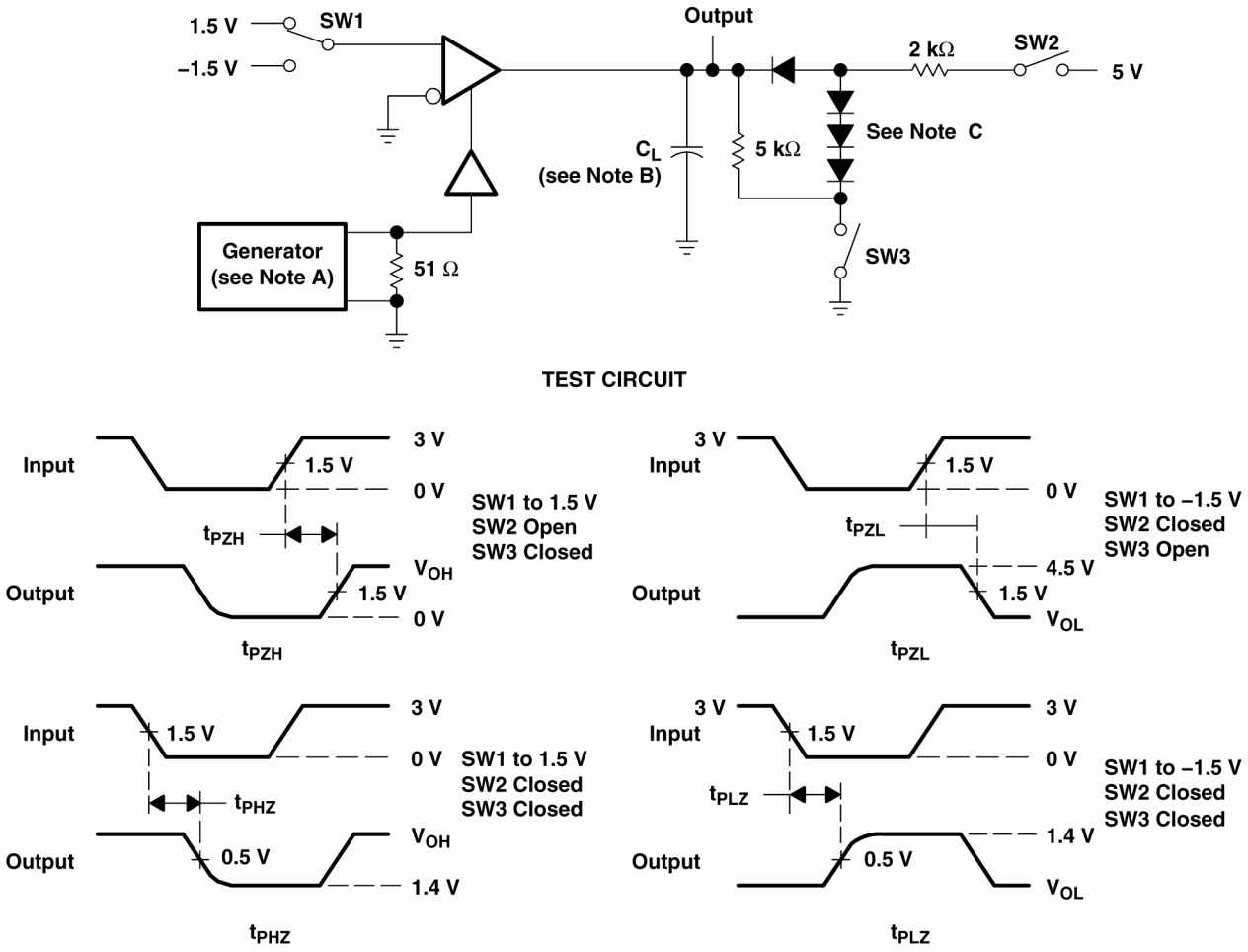
Figure 6-1. V_{OH}, V_{OL}



A. The input pulse is supplied by a generator having the following characteristics: PRR ≤ 1 MHz, duty cycle = 50%, t_r ≤ 6 ns, t_f ≤ 6 ns, Z_O = 50 Ω.

B. C_L includes probe and stray capacitance.

Figure 6-2. Test Circuit and Voltage Waveforms



A. The input pulse is supplied by a generator having the following characteristics: PRR ≤ 1 MHz, duty cycle = 50%, t_f ≤ 6 ns, t_r ≤ 6 ns, Z_O = 50 Ω.

B. C_L includes probe and stray capacitance.

C. All diodes are 1N916 or equivalent.

Figure 6-3. Test Circuit and Voltage Waveforms

7 Detailed Description

7.1 Device Functional Modes

Table 7-1. Function Table (Each Receiver)

DIFFERENTIAL A – B[1]	ENABLE	OUTPUT Y
$V_{ID} \geq 0.2$ V	H	H
-0.2 V < V_{ID} < 0.2 V	H	?
$V_{ID} \leq -0.2$ V	H	L
X	L	Z
Open circuit	H	?

(1) H = high level, L = low level, ? = indeterminate, X = irrelevant, Z = high impedance (off)

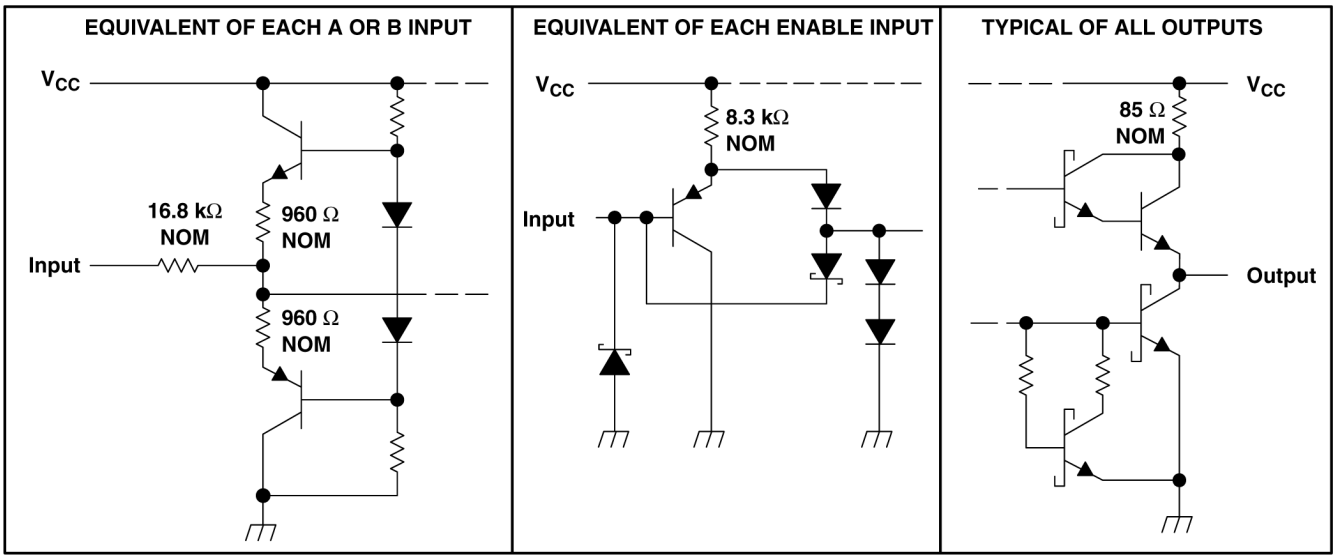


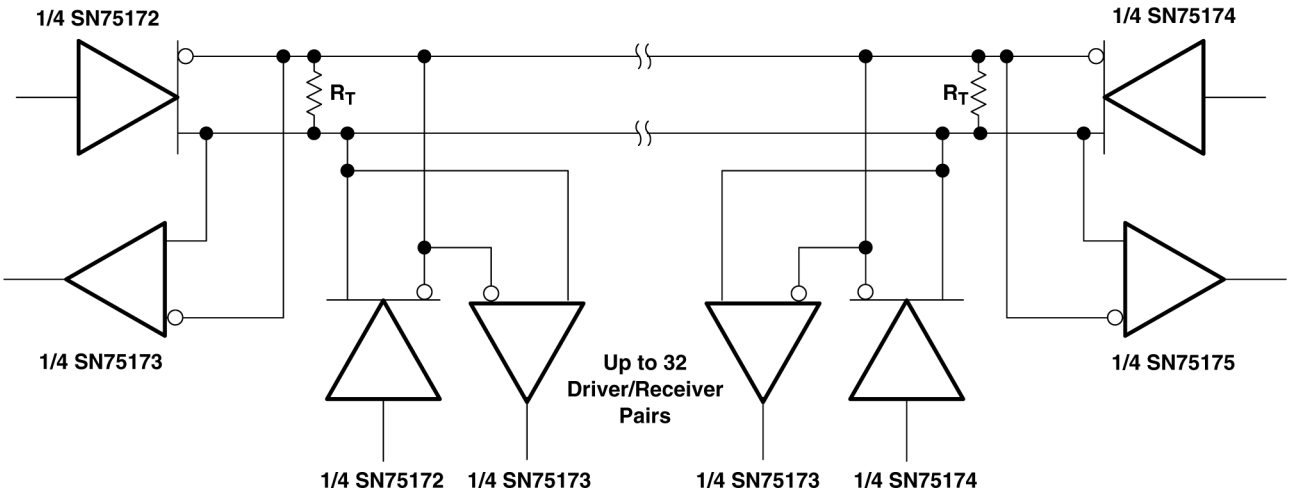
Figure 7-1. Schematics of Inputs and Outputs

8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information



A. The line should be terminated at both ends in its characteristicc impedance ($R_T = Z_O$). Stub lengths off the main line should be kept as short as possible.

Figure 8-1. Typical Application Circuit

9 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

9.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.2 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

9.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.
All trademarks are the property of their respective owners.

9.4 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.5 Glossary

TI Glossary	This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision C (November 2006) to Revision D (October 2023)	Page
• Changed the numbering format for tables, figures, and cross-references throughout the document	1

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
SN65175D	Active	Production	SOIC (D) | 16	40 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	SN65175
SN65175D.A	Active	Production	SOIC (D) | 16	40 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	SN65175
SN65175DR	Active	Production	SOIC (D) | 16	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	SN65175
SN65175DR.A	Active	Production	SOIC (D) | 16	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	SN65175
SN75175D	Obsolete	Production	SOIC (D) | 16	-	-	Call TI	Call TI	0 to 70	SN75175
SN75175DR	Active	Production	SOIC (D) | 16	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75175
SN75175DR.A	Active	Production	SOIC (D) | 16	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75175
SN75175N	Active	Production	PDIP (N) | 16	25 | TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	SN75175N
SN75175N.A	Active	Production	PDIP (N) | 16	25 | TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	SN75175N
SN75175NSR	Active	Production	SOP (NS) | 16	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75175
SN75175NSR.A	Active	Production	SOP (NS) | 16	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75175
SN75175NSRG4	Active	Production	SOP (NS) | 16	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75175

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

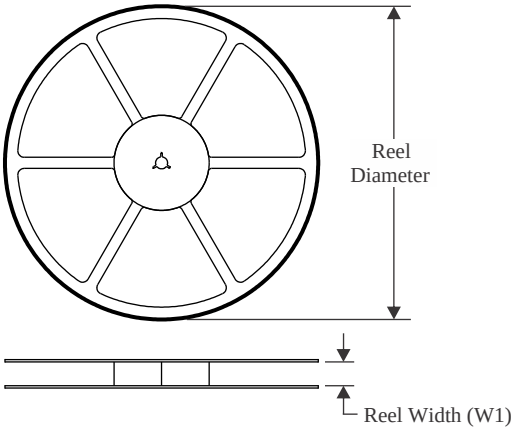
(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

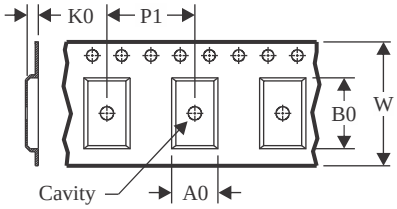
Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

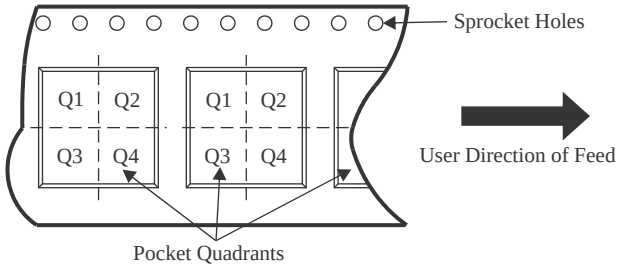


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

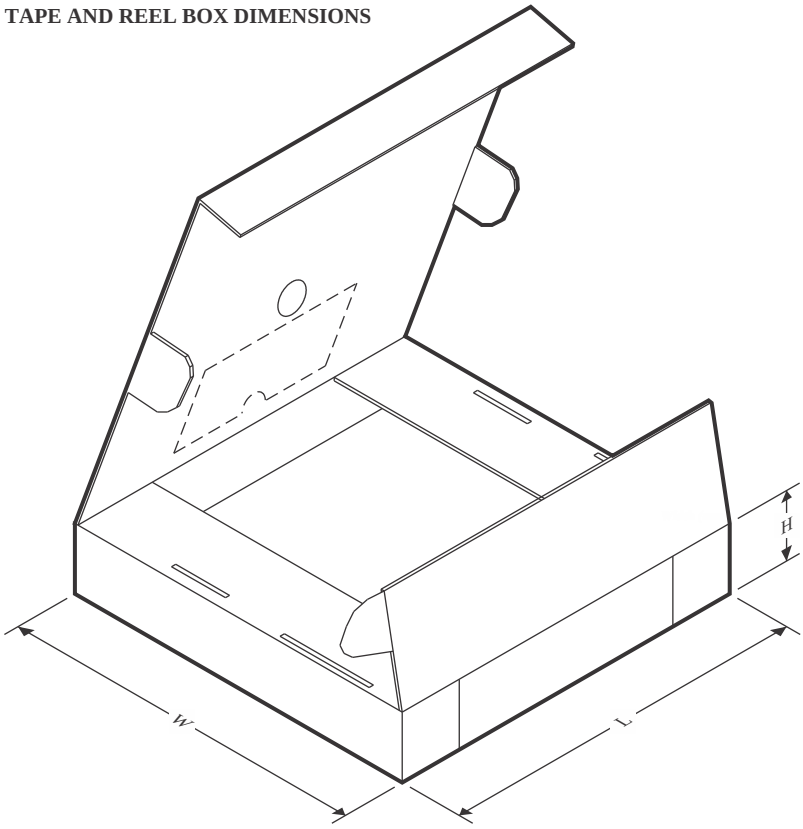
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65175DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN75175DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN75175NSR	SOP	NS	16	2000	330.0	16.4	8.1	10.4	2.5	12.0	16.0	Q1

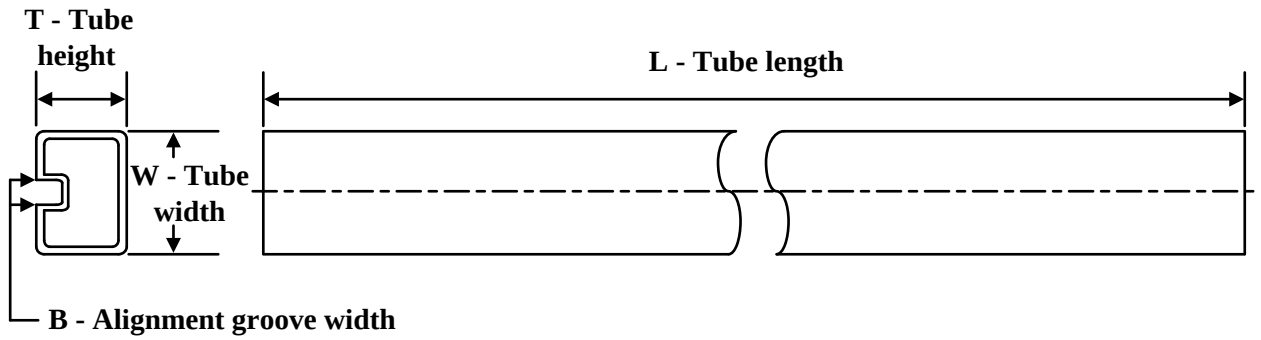
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65175DR	SOIC	D	16	2500	353.0	353.0	32.0
SN75175DR	SOIC	D	16	2500	353.0	353.0	32.0
SN75175NSR	SOP	NS	16	2000	353.0	353.0	32.0

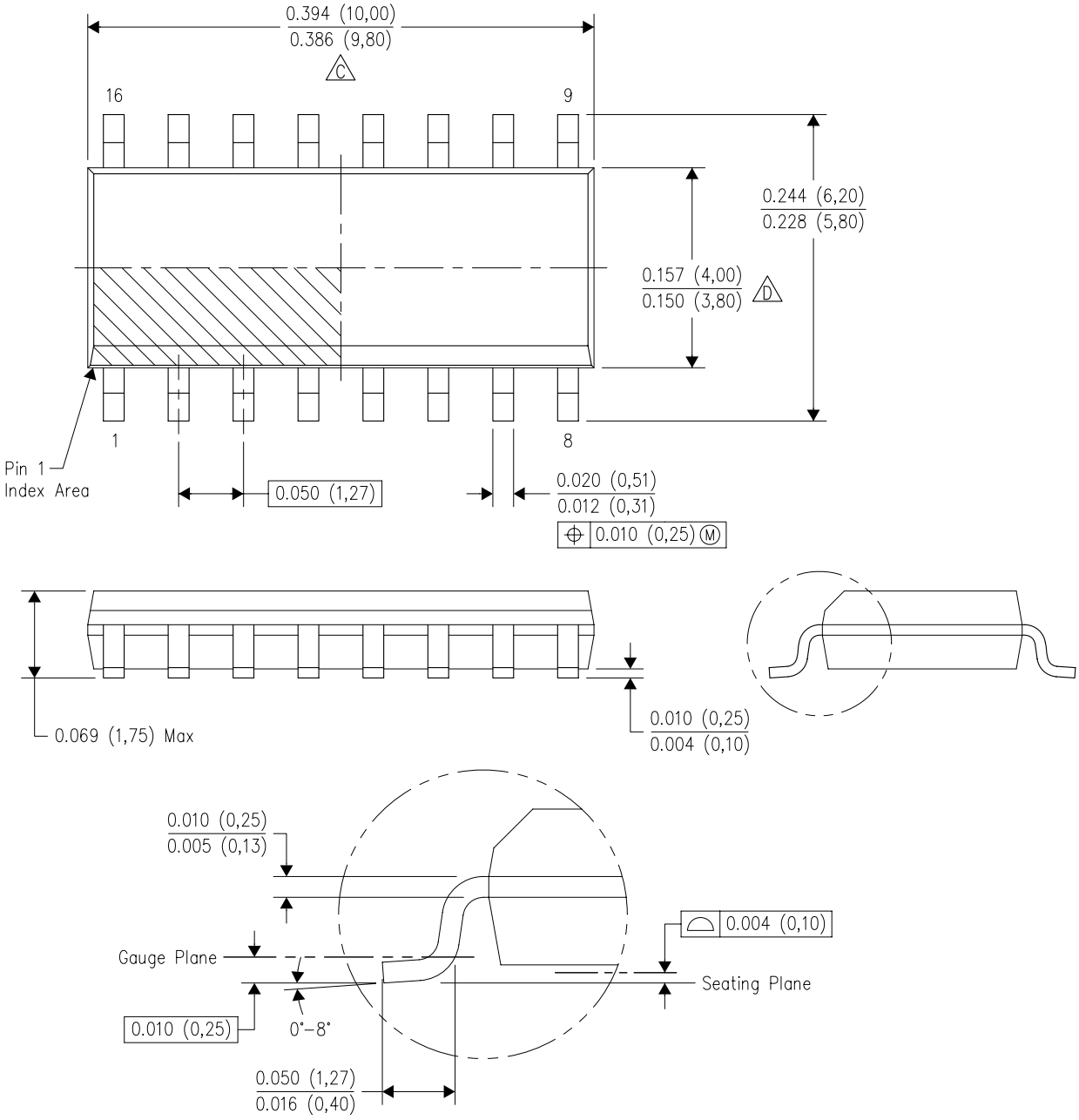
TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN65175D	D	SOIC	16	40	507	8	3940	4.32
SN65175D.A	D	SOIC	16	40	507	8	3940	4.32
SN75175N	N	PDIP	16	25	506	13.97	11230	4.32
SN75175N.A	N	PDIP	16	25	506	13.97	11230	4.32

D (R–PDSO–G16) PLASTIC SMALL OUTLINE

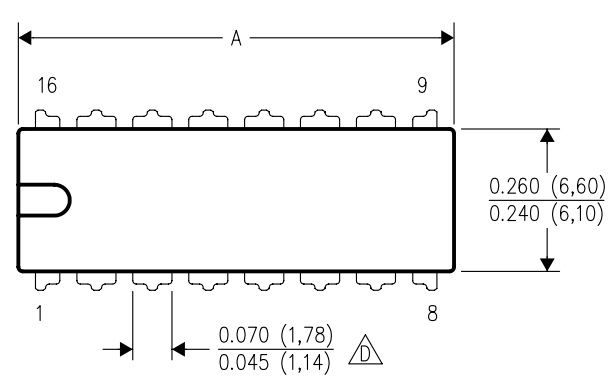


NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AC.

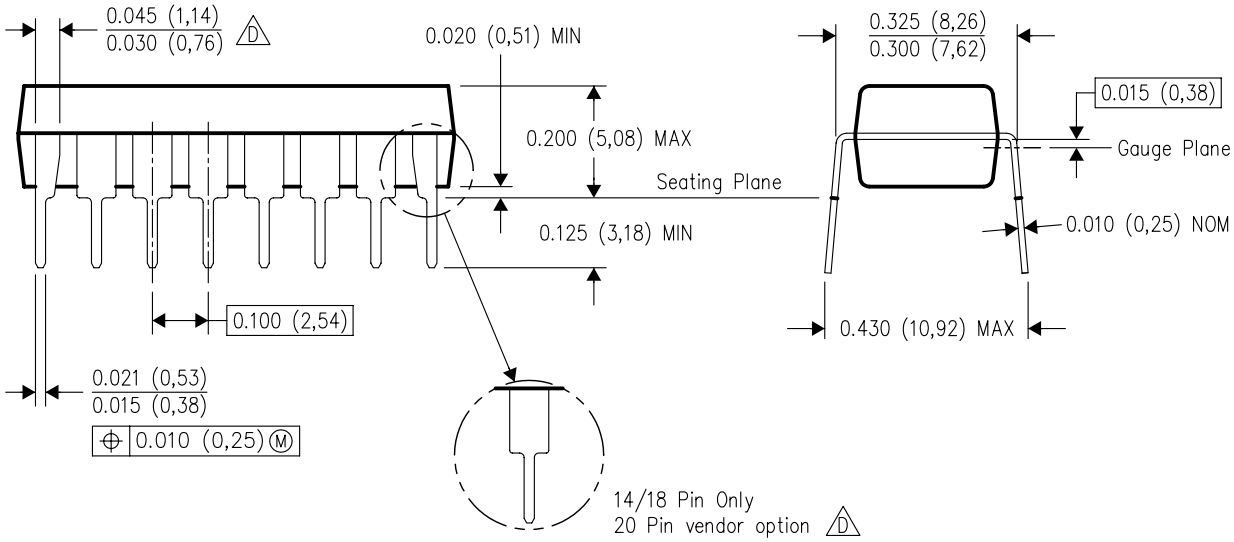
N (R–PDIP–T**)

PLASTIC DUAL–IN–LINE PACKAGE

16 PINS SHOWN

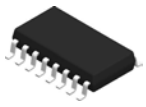


DIM \ PINS **	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS–001 VARIATION (C)	AA	BB	AC	AD



4040049/E 12/2002

NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS–001, except 18 and 20 pin minimum body length (Dim A).
D. The 20 pin end lead shoulder width is a vendor option, either half or full width.

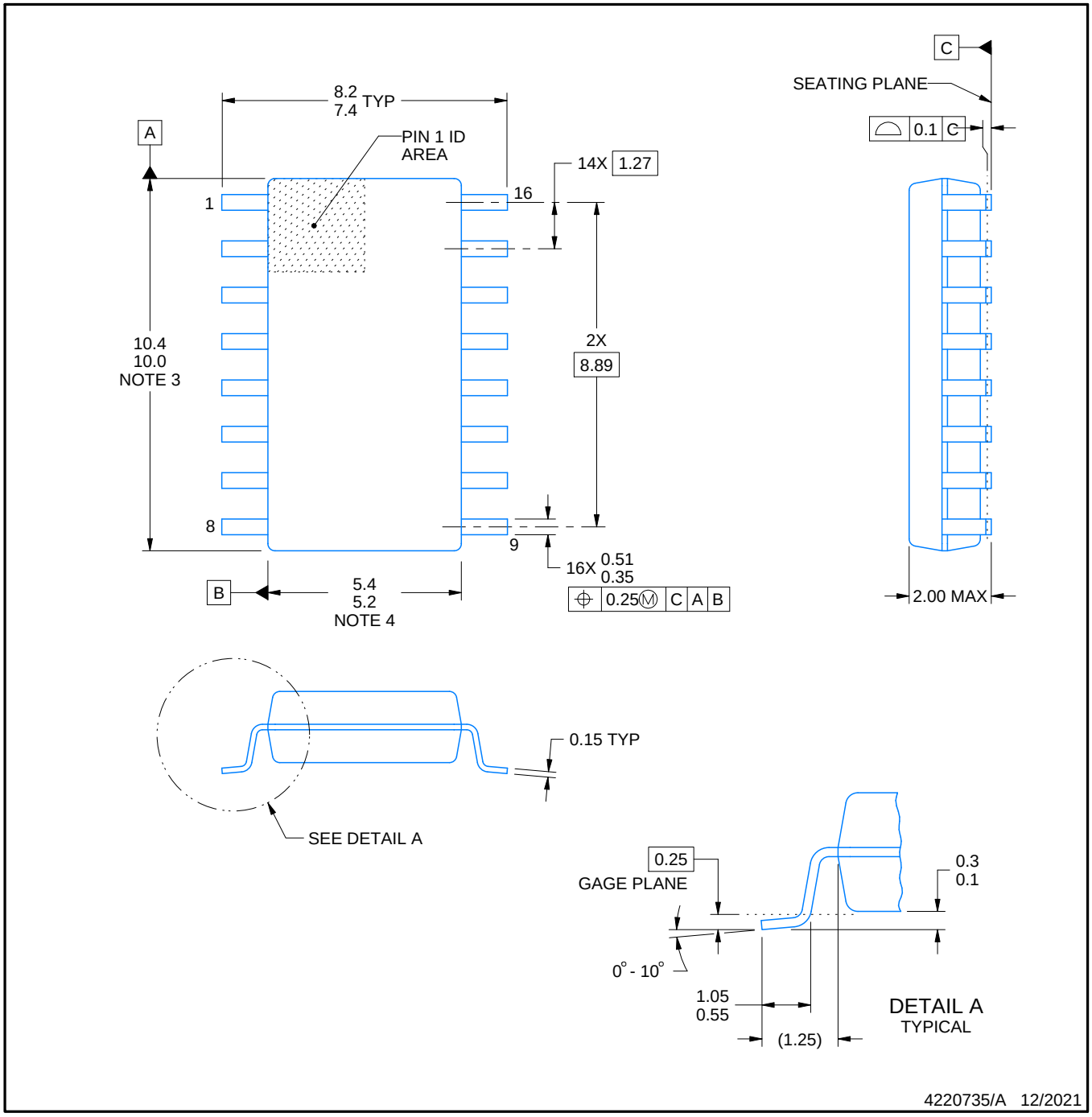


PACKAGE OUTLINE

NS0016A

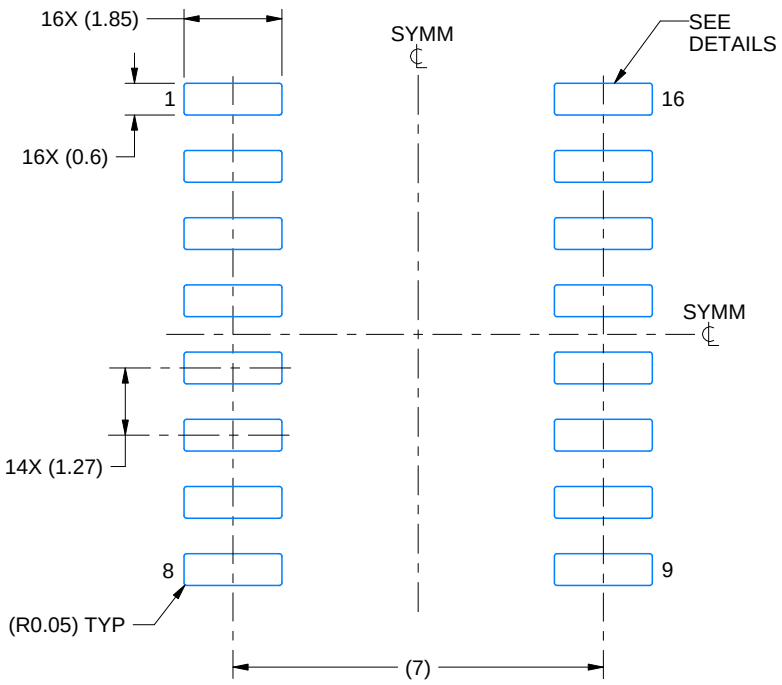
SOP - 2.00 mm max height

SOP

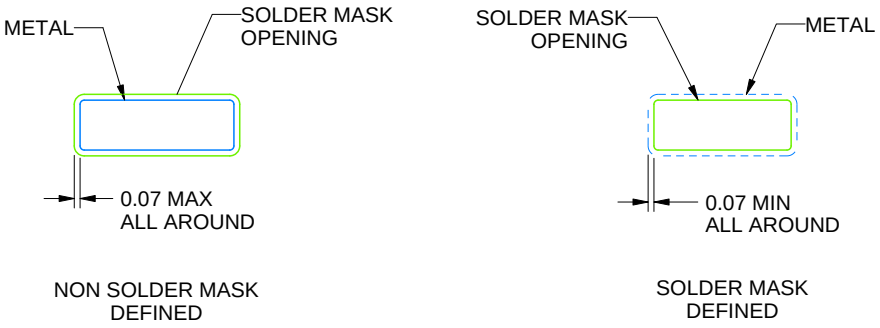


NOTES:

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.



LAND PATTERN EXAMPLE
SCALE:7X



NON SOLDER MASK
DEFINED

SOLDER MASK
DEFINED

SOLDER MASK DETAILS

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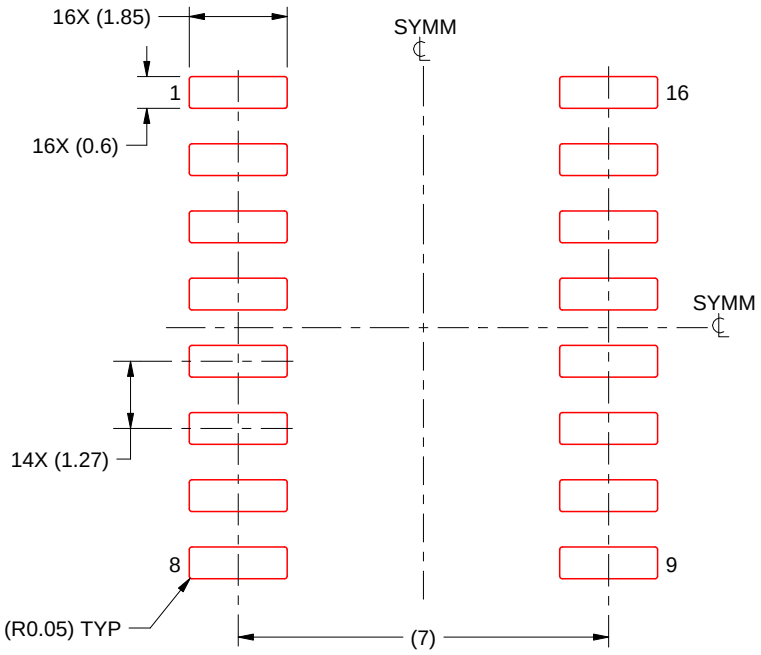
NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:7X

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NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

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